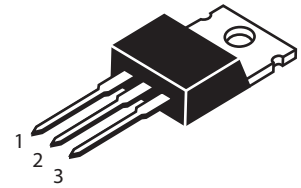


### PNP/NPN Silicon Power Transistor

**(Pb)** Lead(Pb)-Free

#### FEATURES:

- \* Medium Power Complementary silicon transistors
- \* TIP120,121,122 Darlington TRANSISTOR (NPN)
- \* TIP125,126,127 Darlington TRANSISTOR (PNP)



1. BASE  
2. COLLECTOR  
3. EMITTER

**TO-220**

#### MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise noted)

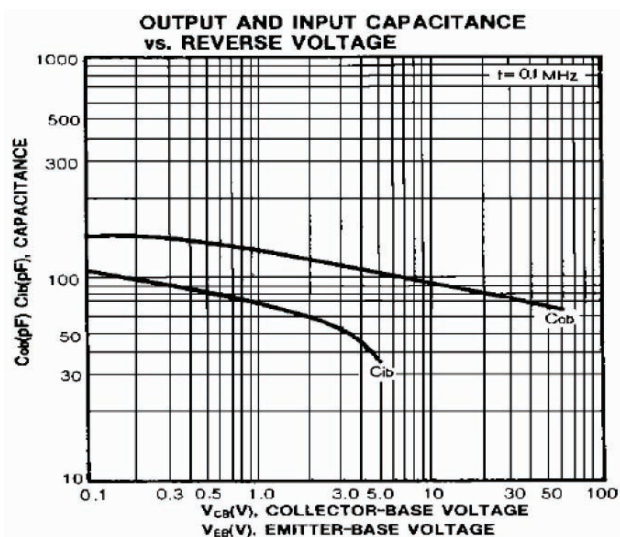
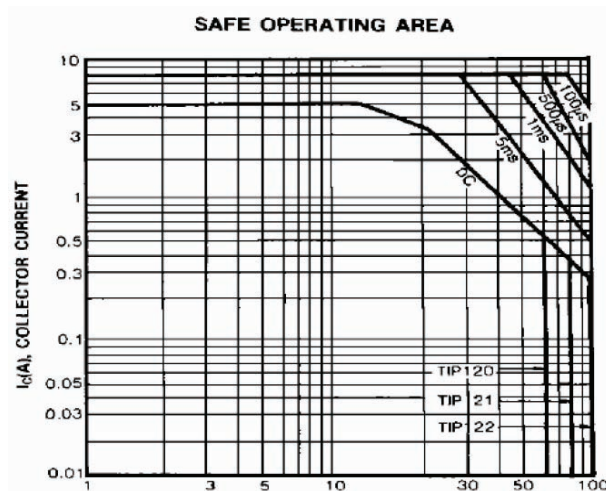
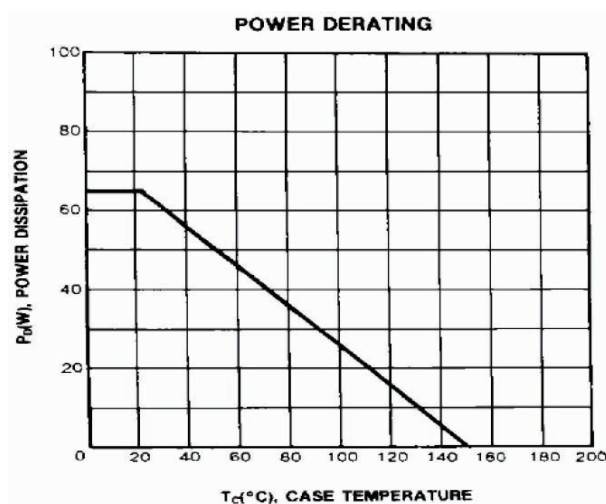
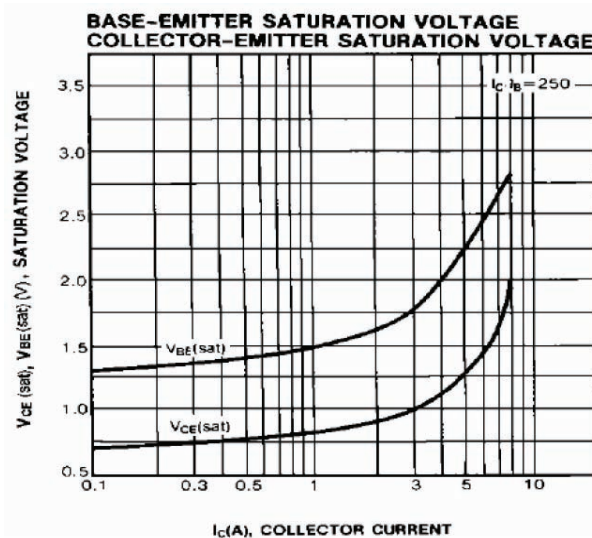
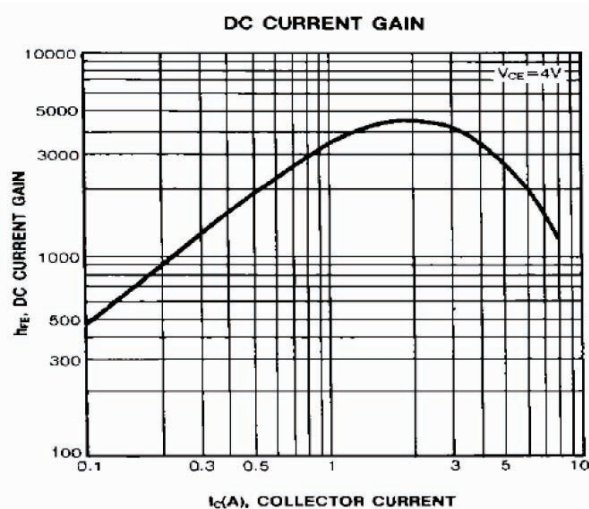
Symbol	Parameter	TIP120 TIP125	TIP121 TIP126	TIP122 TIP127	Units
V <sub>CBO</sub>	Collector-Base Voltage	60	80	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	60	80	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	5			V
I <sub>C</sub>	Collector Current -Continuous	5			A
P <sub>C</sub>	Collector Power Dissipation	2			W
R <sub>θJA</sub>	Thermal Resistance Junction to Ambient	62.5			°C/W
R <sub>θJC</sub>	Thermal Resistance Junction to Case	1.92			°C/W
T <sub>J</sub>	Junction Temperature	150			°C
T <sub>stg</sub>	Storage Temperature	-55-150			°C

#### ELECTRICAL CHARACTERISTICS (T<sub>amb</sub>=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	V <sub>(BR)CBO</sub>	I <sub>C</sub> =1mA, I <sub>E</sub> =0	60 80 100		V
Collector-emitter breakdown voltage TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	V <sub>CEO(SUS)</sub>	I <sub>C</sub> =30mA, I <sub>B</sub> =0	60 80 100		V
Collector cut-off current TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	I <sub>CBO</sub>	V <sub>CB</sub> =60V, I <sub>E</sub> =0 V <sub>CB</sub> =80V, I <sub>E</sub> =0 V <sub>CB</sub> =100V, I <sub>E</sub> =0		0.2	mA
Collector cut-off current TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	I <sub>CEO</sub>	V <sub>CE</sub> =30V, I <sub>B</sub> =0 V <sub>CE</sub> =40V, I <sub>B</sub> =0 V <sub>CE</sub> =50V, I <sub>B</sub> =0		0.5	mA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0		2	mA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =3V, I <sub>C</sub> =0.5A	1000		
	h <sub>FE(2)</sub>	V <sub>CE</sub> =3V, I <sub>C</sub> =3A	1000		
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =3A, I <sub>B</sub> =12mA I <sub>C</sub> =5A, I <sub>B</sub> =20mA		2 4	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> =3V, I <sub>C</sub> =3A		2.5	V
Output Capacitance TIP125,TIP126,TIP127 TIP120,TIP121,TIP122	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0A f = 0.1MHz		300 200	pF

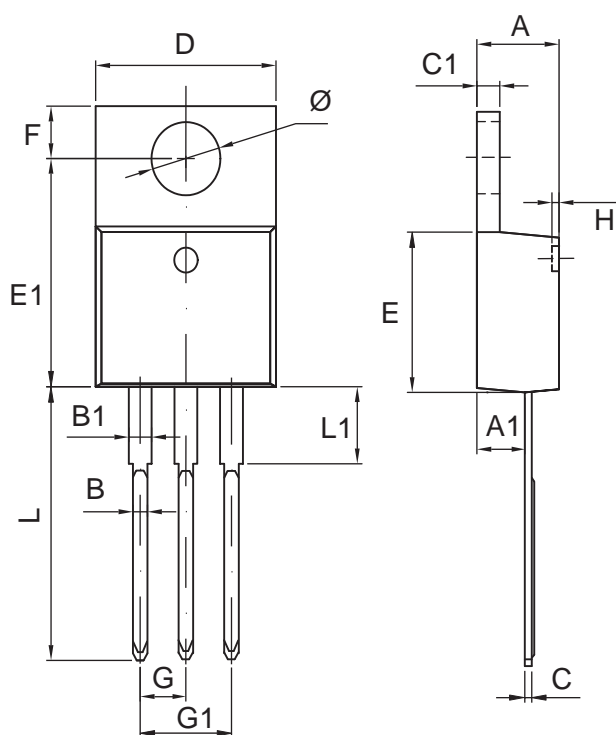
## Typical Characteristics

## TIP120,121,122,125,126,127



## TO-220 Outline Dimensions

unit:mm



TO-220		
Dim	Min	Max
A	4.47	4.67
A1	2.52	2.82
B	0.71	0.91
B1	1.17	1.37
C	0.31	0.53
C1	1.17	1.37
D	10.01	10.31
E	8.50	8.90
E1	12.06	12.446
G	2.54 TYP	
G1	4.98	5.18
F	2.59	2.89
H	0.00	0.30
L	13.4	13.8
L1	3.56	3.96
$\Phi$	3.73	3.93